Unit: mm

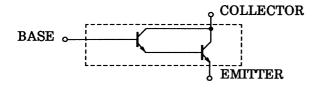
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process) (Darlington)

2SC982TM

Printer Drive, Core Drive and LED Drive Applications Low Frequency Amplifier Applications

• High DC current gain: h_{FE} (1) = 5000 (min) (I_C = 10 mA) : h_{FE} (2) = 10000 (min) (I_C = 100 mA)

Equivalent Circuit



Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	40	V	
Collector-emitter voltage		V_{CEO}	40	V	
Emitter-base voltage		V_{EBO}	10	V	
Collector current	DC	I _C	300	mA	
	Pulsed (Note)	I _{CP}	500		
Base current		Ι _Β	10	mA	
Collector power dissipation		PC	400	mW	
Junction temperature		Tj	125	°C	
Storage temperature range		T _{stg}	-55~125	°C	

1. EMITTER 2. COLLECTOR 3. BASE

TO-92

SC-43

2-5F1B

Weight: 0.21 g (typ.)

JEDEC

JEITA

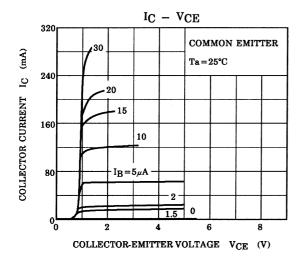
TOSHIBA

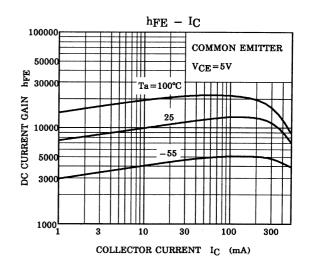
Note: Pulse width \leq 10 ms, duty cycle \leq 10%

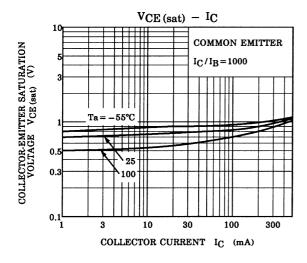
Electrical Characteristics (Ta = 25°C)

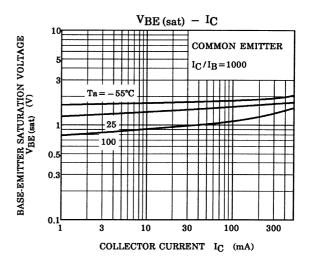
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 40 V, I _E = 0	_	_	0.1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = 8 \text{ V}, I_{C} = 0$	_	_	0.1	μΑ
DC current gain	h _{FE (1)}	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	5000	_	_	
	h _{FE (2)}	$V_{CE} = 2 \text{ V, } I_{C} = 100 \text{ mA}$	10000	_		
Collector-emitter saturation voltage	V _{CE (sat)}	$I_C = 300 \text{ mA}, I_B = 0.3 \text{ mA}$	_	0.9	1.3	V
Base-emitter voltage	V_{BE}	$V_{CE} = 2 \text{ V}, I_{C} = 100 \text{ mA}$	_	1.25	1.6	V

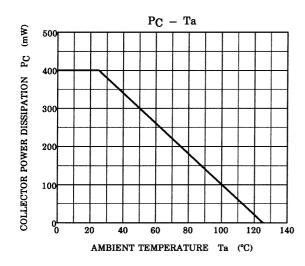
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